Amendments to the Claims:

Please amend claims 1, 3-8, 11 and 12, add claims 16-19, and cancel claim 2 as shown in the following listing of claims. This listing of claims will replace all prior versions, and listings, of claims in the application:

Listing of Claims:

1. (currently amended) Antenna configuration for a telecommunication device ~~(TCD),~~ wherein the antenna configuration ~~comprising~~ comprises a first resonator structure ~~and,~~ a second resonator structure ~~(RS),~~ and a control electrode, wherein said two resonator structures are capacitive coupled to one another ~~and,~~ said control electrode being provided and realized ~~to~~ for changing the capacitive coupling between the first resonator structure ~~an~~ and the second resonator structure, ~~(RS)~~ and ~~wherein~~ the control electrode being contactable from outside the antenna configuration, ~~and~~ wherein a switching means ~~being~~ is associated with the control electrode, by means of the switching means the control electrode being connectable to a reference potential ~~(G)~~, wherein the switching means is part of the antenna configuration.

2. (canceled).

3. (currently amended) Antenna configuration according to claim 1, wherein the switching means ~~being~~ is designed to connect the control electrode to ground ~~(G)~~.

4. (currently amended) Antenna configuration according to claim 1, wherein the antenna configuration ~~being~~ is realized by means of a planar inverted F antenna or a shorted patch antenna or a stub antenna.

5. (currently amended) Antenna configuration according to claim 1, wherein ~~30~~ the antenna configuration ~~comprising~~ comprises a dielectric substrate retaining the first resonator structure and the second resonator structure ~~(RS)~~, the first resonator structure

being connected to a feed line provided on the dielectric substrate, and the second resonator structure ~~(RS)~~, by means of the dielectric substrate being electrically isolated from the first resonator structure and being located adjacent to the first resonator structure, being connected to ground ~~(G)~~.

6. (currently amended) Antenna configuration according to claim 5, wherein the first resonator structure and the second resonator structure ~~(RS)~~ are realized by printed structures printed on a surface of the dielectric substrate.

7. (currently amended) Antenna configuration according to claim 5, wherein the first resonator structure and the second resonator structure ~~(RS)~~ are at least partially located in the interior of the dielectric substrate.

8. (currently amended) Antenna configuration ~~(1)~~ according to claim 7, wherein the antenna configuration ~~being~~ is manufactured by usage of low temperature cofired ceramic technology.

9. (previously presented) Antenna configuration according to claim 1, wherein the switching means comprises a PIN diode or a semiconductor switch.

10. (previously presented) Antenna configuration according to claim 1, wherein the switching means comprises a variable capacitance diode.

11. (currently amended) Telecommunication device ~~(TCD)~~, comprising an antenna configuration according to claim 1.

12. (currently amended) Method of operating a telecommunication device comprising an antenna configuration according to claim 1, wherein the antenna configuration comprises a control electrode, wherein said control electrode is contacted from outside the antenna configuration and for changing the resonance frequency of the antenna configuration,

wherein contacting of the control electrode from outside is done by switchably connecting the control electrode ~~30~~ to a reference potential ~~(G)~~.

13. (original) Method according to claim 12, wherein the resonance frequency is changed between a first frequency band and a second frequency band.

14. (original) Method according to claim 13, wherein the resonance frequency is changed between the DCS band and the UMTS band.

15. (original) Method according to claim 12, wherein the resonance frequency is changed within a given frequency band between a first sub-band and a second sub-band.

16. (new) Method according to claim 12, wherein the resonance frequency is changed in discrete steps, wherein the resonance frequency is changed a fixed amount in each of the discrete steps.

17. (new) Antenna configuration according to claim 5, wherein the dielectric substrate includes multiple sintered layers of ceramic foils.

18. (new) Antenna configuration for a telecommunication device, wherein the antenna configuration comprises a first resonator structure, a second resonator structure, and a control electrode, wherein said two resonator structures are capacitive coupled to one another, said control electrode being provided and realized for changing the capacitive coupling between the first resonator structure and the second resonator structure, and the control electrode being contactable from outside the antenna configuration, wherein a switching means is associated with the control electrode, by means of the switching means the control electrode being connectable to a reference potential, wherein the antenna configuration is realized by means of a planar inverted F antenna or a stub antenna.

19. (new) Antenna configuration for a telecommunication device, wherein the antenna configuration comprises a first resonator structure, a second resonator structure, and a control electrode, wherein said two resonator structures are capacitive coupled to one another, said control electrode being provided and realized for changing the capacitive coupling between the first resonator structure and the second resonator structure, and the control electrode being contactable from outside the antenna configuration, wherein a switching means is associated with the control electrode, by means of the switching means the control electrode being connectable to a reference potential, wherein the antenna configuration comprises a dielectric substrate retaining the first resonator structure and the second resonator structure, the first resonator structure being connected to a feed line provided on the dielectric substrate, and the second resonator structure, by means of the dielectric substrate being electrically isolated from the first resonator structure and being located adjacent to the first resonator structure, being connected to ground.